

Complementary Silicon Plastic Power Transistors

... designed for use as high-frequency drivers in audio amplifiers.

- DC Current Gain Specified to 4.0 Amperes
 $h_{FE} = 40$ (Min) @ $I_C = 3.0$ Adc
 $= 20$ (Min) @ $I_C = 4.0$ Adc
- Collector–Emitter Sustaining Voltage —
 $V_{CEO(sus)} = 120$ Vdc (Min) — MJE15028, MJE15029
 $= 150$ Vdc (Min) — MJE15030, MJE15031
- High Current Gain — Bandwidth Product
 $f_T = 30$ MHz (Min) @ $I_C = 500$ mAcd
- TO–220AB Compact Package

MAXIMUM RATINGS

Rating	Symbol	MJE15028 MJE15029	MJE15030 MJE15031	Unit
Collector–Emitter Voltage	V_{CEO}	120	150	Vdc
Collector–Base Voltage	V_{CB}	120	150	Vdc
Emitter–Base Voltage	V_{EB}	5.0		Vdc
Collector Current — Continuous — Peak	I_C	8.0 16		Adc
Base Current	I_B	2.0		Adc
Total Power Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	50 0.40		Watts W/ $^\circ\text{C}$
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above 25°C	P_D	2.0 0.016		Watts W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–65 to +150		$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	$R_{\theta JC}$	2.5	$^\circ\text{C/W}$
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	62.5	$^\circ\text{C/W}$

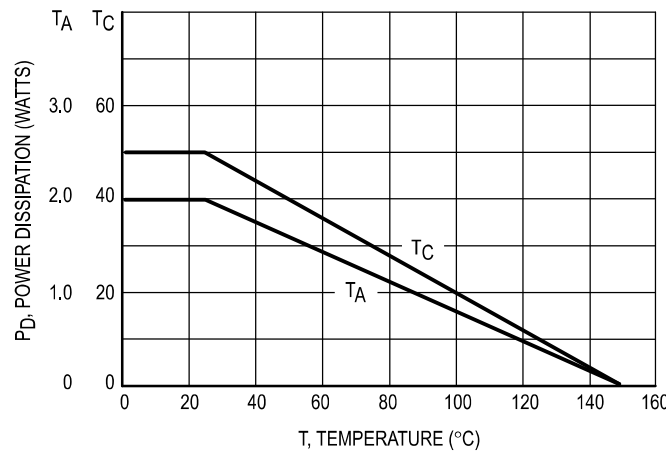


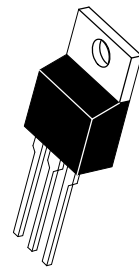
Figure 1. Power Derating

Preferred devices are Motorola recommended choices for future use and best overall value.

NPN
MJE15028*
MJE15030*
PNP
MJE15029*
MJE15031*

*Motorola Preferred Device

8 AMPERE
POWER TRANSISTORS
COMPLEMENTARY
SILICON
120–150 VOLTS
50 WATTS



CASE 221A–06
TO–220AB